TOSHIBA BI-CMOS INTEGRATED CIRCUIT SILICON MONOLITHIC

TB6500AH

2 PHASE BIPOLAR STEPPER + FULL BRIDGE DRIVER

The TB6500AH is Stepping Motor Driver IC incorporates Dual Bipolar Stepping Motor Drivers.

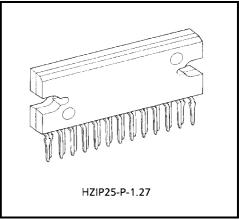
DC Motor Driver and Serial to Parallel signal conversion circuit (12bit Serial to Parallel shift Resistor with Latch) which control the 3 output drivers states by means of input serial signal trains.

FEATURES

- Package : HZIP25-P
- All CMOS compatible input
- 2 Bipolar Stepping Motors and 1 Full Bridge Motor are controlled by input serial signal trains.
- Output current up to 0.8 A (for Stepper) and 0.6 A (for DC Motor)
- PWM chopper type Stepping Motor Drivers.
- Wide range of operating supply voltage $: V_M = 0 \sim 27 V$

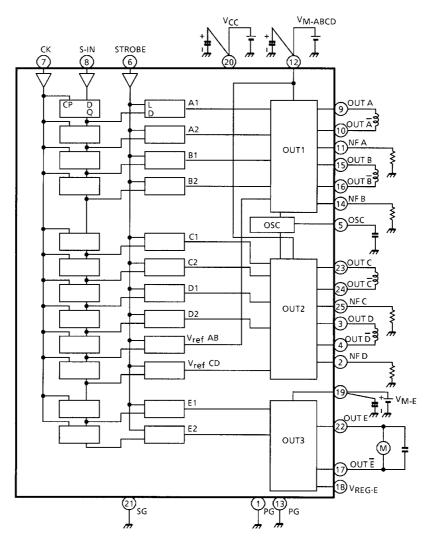
:
$$V_{CC} = 4.5 \sim 5.5 V$$

• Built-in thermal shut down, power supply monitor circuit.



Weight: 9.86 g (Typ.)

TOSHIBA BLOCK DIAGRAM



Capacitance connect to each power supply terminal is required to change to optimum value for noise elimination and also required to connect directly to each power supply terminal (V_{CC} , V_M) and the corresponding GND terminal (see Table 1) for stable operations.

Table 1

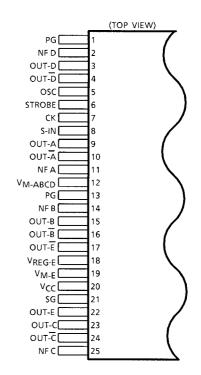
GND	POWER SUPPLY
Pin (21)	Pin (20) (V _{CC})
Pin (13)	Pin (12) (V _{M-ABCD})
Pin (1)	Pin (19) (V _{M-E})

Heat Fin is connect to GND terminal with Low Impedance.

PIN FUNCTION

PIN No. SY		
	'MBOL	FUNCTIONAL DESCRIPTION
1	PG	Power GND terminal
2 1	NF D	D channel current detective terminal
3 O	UT-D	Output D channel
4 OI	UT-D	Output D channel
5	OSC	Internal oscillation frequency setting terminal
6 ST	ROBE	STROBE signal input terminal
7	СК	CLOCK signal input terminal
8 3	S-IN	Serial signal input terminal
9 O	UT-A	Output A channel
10 OI	JT-Ā	Output A channel
11 1	NF A	A channel current detective terminal
12 V _N	1-ABCD	Power voltage supply terminal for motor driver
13	PG	Power GND terminal
14 I	NF B	B channel current detective terminal
15 O	UT-B	Output B terminal
16 OI	UT-B	Output B terminal
17 OI	UT-Ē	Output E terminal
18 V	REG·E	External reference voltage input terminal
19 \	∕ _{M−E}	Power voltage supply terminal for motor driver
20	V _{CC}	Power voltage supply terminal for control
21	SG	Signal GND terminal
22 O	UT-E	Output E terminal
23 O	UT-C	Output C terminal
24 OI	UT-Ē	Output \overline{C} terminal
25 1	NF C	C channel current detective terminal

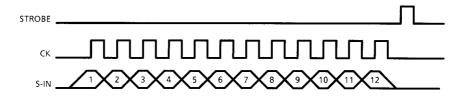
PIN CONNECTION



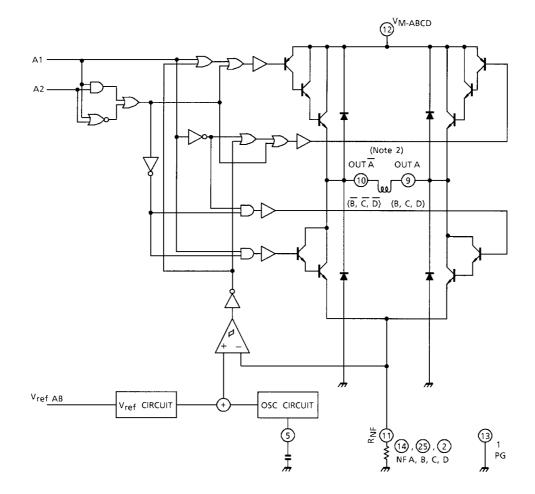
INPUT SERIAL PULSE TRAIN AND POWER OUTPUT STATES

SERIAL INPUT SIGNAL TRAIN		CONTROL		OPER		OPERA	TION	
				INF	PUT	OUT	PUT	MODE
1	E2			E1	E2	E	Ē	MODE
				L	L	∞	8	STOP
		DC motor control		Н	L	Н	L	CW / CCW
2	E1			L	Н	L	Н	CCW / CW
2	Z EI			Н	Н	L	L	BREAK
3	V _{ref} .CD	Stepping motor 2 chapping rate control (V _{ref} CD)	Vr	_{ef} = 0.85 V	(Typ.) (at "	H" mode)		
4	V _{ref} .AB	Stepping motor 1 chapping rate control (V _{ref} AB)	Vr	V _{ref} = 0.65 V (Typ.) (at "L" mode)				
5	D2							
6	D1	Stepping motor 2 control		A1	PUT A2	A 001		MODE
7	C2	(Out C, D)		L	L	~ ~	8	STOP
8	C1			H	L	н Н	L	CW / CCW
9	B2			L	н	L	н	
10	B1			- H	H	~	∞	STOP
		Stepping motor 1 control (Out A, B)		D4 D2				
11	A2				$B \to B, \overline{B}$ $B \to C, \overline{C}$			
12	A1		$D1, D2 \rightarrow D, \overline{D}$					
12				are all the same.				

INPUT SERIAL PULSE TRAIN TIMING CHART



OUTPUT STAGE 1, 2 1/2 CIRCUIT



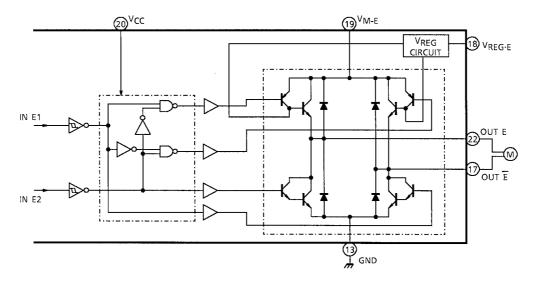
FUNCTION (Comp.+ > Comp. -) Note 1

A1	A2	OUT A	OUT Ā	MODE
L	L	8	8	STOP
Н	L	Н	L	CW / CCW
L	Н	L	Н	CCW / CW
Н	Н	8	8	STOP

Note 1: In case of Comp.+ < Comp. –, Upper side power transistor turned off.

Note 2: Free wheeling diode connects between output A terminal and GND is required for stable operating. And also recommend to connect free wheeling diodes other output terminals for reliable operations.

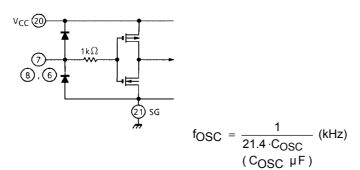
OUTPUT STAGE 3



FUNCTION

INF	PUT	OU	TPUT	MODE	
IN E1	IN E2	OUT E	OUTĒ	MODE	
L	L	8	8	STOP	
Н	L	Н	L	CW / CCW	
L	Н	L	Н	CCW / CW	
Н	Н	L	L	BREAK	

INPUT STAGE (CK, S-IN, STROBE terminal)



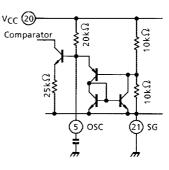
MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage (Motor)	V _M	30	V
Supply Voltage (Control)	V _{CC}	7.0	V
Input Voltage	V _{IN} 7.0		V
Output Output	IO ABCD	±0.8	^
Output Current	I _{O E}	±0.6	A
Dewer Dissinction	D-	43 (Note)	w
Power Dissipation	PD	5	vv
Operating Temperature	T _{opr}	-40~85	°C
Storage Temperature	T _{stg}	-55~150	°C

Note: Tc = 85°C

- ∞ : High Impedance
- Note: Inputs are all high active type

OSC STAGE (OSC terminal)



RECOMMENDED OPERATING CONDITION (Ta = -20~75°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT	
Supply Voltage (C	Control)	V _{CC}		4.5	5.0	5.5	V	
Supply Voltage (M	1otor)	V _M		21.6	24	26.4	V	
Input Voltage		VIN		0	_	V _{CC}	V	
Quitout Current	IOUT ABCD	1		—	_	0.7	A	
Output Current	IOUT E	lout		_	_	0.6		
		fск		_	_	1.0	MHz	
Clock Frequency		f STROBE		_	_	1.0		
Clock Pulse Width		tw _{CK}		500	_	_	- ns	
CIOCK FUISE WILLI	I	twstrobe		500	_	_		
Data Sat Un Tima		tsu _{CK} –s⋅IN			_	_		
Data Set Up Time		tsu _{ST-CK}		250	_	_		
Data Hold Time		th _{CK-S·IN}		250	_	_	ns	
		th _{ST-CK}		250	_	_		
PWM Oscillation F	Frequency	f _{PWM}		20	_	100	kHz	

ELECTRICAL CHARACTERISTICS

Output stage (Ta = 25° C, V_{CC} = 5 V, V_M = 24 V)

CHARAC	TERISTIC	SYMBOL	TEST CIR- CUIT	TEST C	CONDITION	MIN	TYP.	MAX	UNIT
Operation Power S	peration Power Supply Voltage V _M (opr.)		0	-	27	V			
	AB			I _{OUT} = 0.7 A	Output-V _M	_	2.2	2.7	
	CD	V _{SATU-1}		I _{OUT} = 0.5 A	Output-VM	_	2.0	2.5	
	AB	V _{SATL-1}		I _{OUT} = 0.7 A	Output-N _F		1.5	2.0	
Saturation	CD	VSATL-1	- 1	I _{OUT} = 0.5 A	Output-N _F		1.3	1.8	v
Voltage	Е	V _{SATU-2}		I _{OUT} = 0.5 A	Output-V _M		2.2	2.7	v
	L	VSA10-2		I _{OUT} = 0.3 A	Output-VM	_	2.0	2.5	-
	Е			I _{OUT} = 0.5 A	- Output-OG		1.5	2.0	
	L	V _{SATL-2}		I _{OUT} = 0.3 A		_	1.2	1.7	
E-ch Output Voltag	10	V _{OE}	1	I _{OUT} = 0.5 A	V _{REG·E} = 15 V		15	—	v
	le.	V0E		I _{OUT} = 0.3 A	VREGE - 13 V		15	—	v
Reference Current		I _{REG}	1	V _{REG·E} = 15	_	50	100	μA	
Reference Voltage		V _{REG·E} (opr.)	1			0	_	22	V
Output Leak Currer		I _{OL-H}	2	V _{CE} = 30 V		_	_	50	μA
	it.	I _{OL-L}				_	_	50	μΑ
	AB	V _{F-U1}				_	1.6	2.0	
Clamp Diode	CD	V _{F-L1}		I _F = 0.7 A, Output A–D		_	1.2	1.6	V
Forward Voltage	E	V _{F-U2}	3	3 I _F = 0.5 A, Output E		—	1.5	1.9	
	L	V _{F-L2}		η _F – 0.5 Α, Ου		_	1.3	1.7	

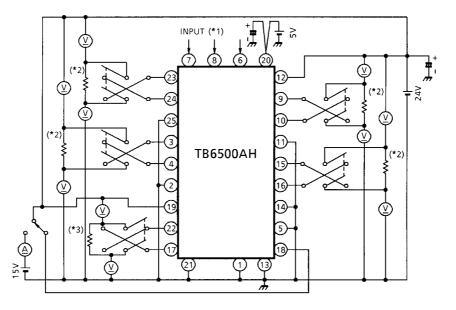
Small signal stage (Ta = 25° C, V_{CC} = 5 V, V_M = 24 V)

CHARACTERISTIC	SYMBOL	TEST CIR- CUIT	TEST CONDITION		MIN	TYP.	MAX	UNIT
Operation Supply Voltage	V _{CC} (opr.)				4.5	_	5.5	V
	I _{CC1}		CK, ST, S-IN : O	pen	_	30	50	
	I _{CC2}		CK : 1 MHz, DAT Output ON	A : 1 / 2 f _{CLK}	_	30	50	
Quiescent Current	ICC3		CK : 1 MHz, DATA Output OFF	A : 1 / 2 f _{CLK}	_	30	50	mA
	IM-ABCD	4	Output open, Input serial signal Output ON (A1, B1, C1, D1 = "H" A2, B2, C2, D2 = "H")		_	30	40	
			Output open Output OFF		_	_	50	μA
			CW, CCW, BREAK Output ON, Output open		_	5	12	mA
	I _{M-E}		Output open Output OFF		_	_	50	μA
less d Malla an	V _{IN (H)}	5	5 CK, S-IN, ST		3.5	_	V _{CC} +0.4	v
Input Voltage	V _{IN (L)}	5			GND -0.4	_	1.5	
land Queen at	I _{IN (H)}	_	V _{INH} = 5.4 V		-3	_	3	
Input Current	I _{IN (L)}	5	V _{INL} = 0.4 V		-3	_	3	μA
	V _{ref (H)}		T _j = −40~125°C	V _{ref} IN = H	0.75	0.85	0.95	
Chopping Voltage Level	V _{ref (L)}	6	$C_{OSC} = 3300 \text{ pF}$ $R_{NF} = 3.3 \Omega$ L = 19.5 mH	V _{ref} IN = L	0.55	0.65	0.75	V
V _{ref} Level Differential Voltage	ΔVchop		V _{ref} (H)-V _{ref} (L)		_	0.2	_	V
Reset Voltage	V _{CCR}	-			3.6	3.8	4.1	V
Min. Reset Pulse	tV _{CCR}	7			_	_	1	μs
Min. PWM Frequency	f _{PWML}	4			_	_	10	kHz
Max. PWM Frequency	f _{PWMH}	4			200	_	_	
Thermal Shut Down	TSD (ON)		 т.		120	140	160	
Thermal Shut Down	TSD (OFF)	_	Тј		110	130	150	°C
Differential Temperature	ΔTSD		TSD (ON)-TSD (OFF)	_	10	_	

AC characteristics (Ta = 25°C, VCC = 5 V)

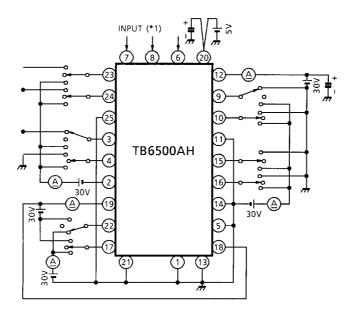
CHARACTERISTIC	SYMBOL	TEST CIR- CUIT	TEST C	ONDITION	MIN	TYP.	MAX	UNIT
CLOCK Frequency	fCK	7			—	—	1.5	MHz
OLOOKTTequency	f STROBE	,			—	—	1.5	1011 12
Min. Clock Pulse Width	t _{CK}	7			340	—	-	ns
	t _{STROBE}	,			340	_		115
Data Set Up Time	t _{suCK} -SIN				170	-		
	t _{suST-CK}	7			170	_		ns
Data Hold Up Time	t _{hCK} -SIN				170	_		
	t _{hST-CK}				170	_	_	
	t _{pLH}	- 7		$\frac{\text{OUT}}{\text{CL}} = 15 \text{ pF}$	—	2	_	- µs
	t _{pHL}		CK-001		_	2	_	
Output Propagation Time	t _{pLH}		STROBE-		_	2	-	
	t _{pHL}		OUT		_	2	-	
	t _{pON-Z}				_	2	_	
	t _{pZ-ON}		V _{CC} ·R-OUT		_	2	_	
Max. Clock Rise Time	t _{rMAX}				_	-	1	
Max. Clock Fall Time	t _{fMAX}				_	-	1	μs
Output Rise Time	tr	7	R _L = 40 Ω		_	1	_	
Output Fall Time	t _f		C _L = 15 pF		_	1	_	
E−ch Output Dead Time	t·dead		R _L = 100 Ω C _L = 15 pF	R _L = 100 Ω C _L = 15 pF		250	_	

TEST CIRCUIT 1 VSATU-1.2, VSATL-1.2



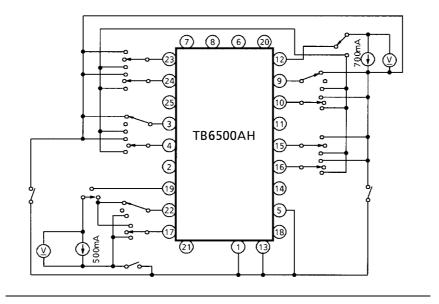
- * 1: Set output transistor active with input mode select.
- * 2: Calibrate output current becomes 0.5 A (or 0.7 A) with this resistor.
- * 3: Calibrate output current becomes 0.3 A (or 0.5 A) with this resistor.

TEST CIRCUIT 2 IOL-H, IOL-L



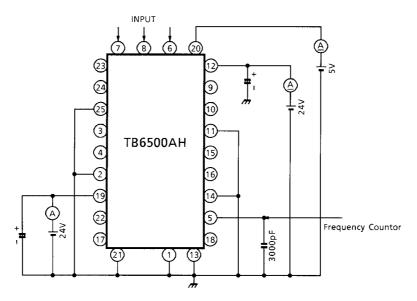
* 1: All "L" level S–IN signal, normal CK and STROBE signals are required to measure.

TEST CIRCUIT 3 VF-U1·2, VF-L1·2

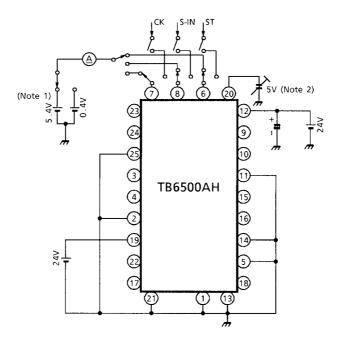


Note: Not to take a GND with any non-connecting pins.

$\textbf{TEST CIRCUIT 4} \quad \textbf{I}_{CC1\cdot 2\cdot 3}, \textbf{I}_M: \textbf{ABCD} \cdot \textbf{E}, \textbf{ f}_{PWML\cdot H}$



TEST CIRCUIT 5 I_{INH} , I_{INL} , V_{INH} , V_{INH} , V_{INL} , V_{CCR}



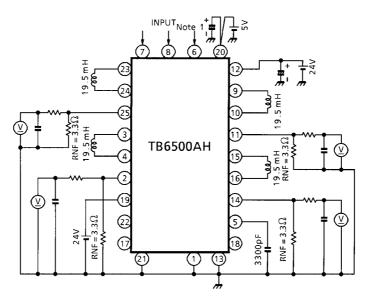
V_{IN} level

Note 1: Apply signals to CK, S-IN, and STROBE at the levels shown in the diagram and check function.

Power supply monitor level

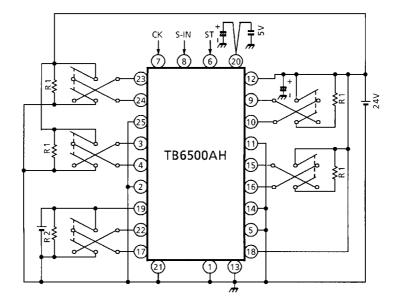
Note 2: Change the power supply voltage and check the output operation.

TEST CIRCUIT 6 V_{refH} , V_{refL} , ΔV_{ref}



Note 1: Hold the state (2 phase excitation mode) and measure.

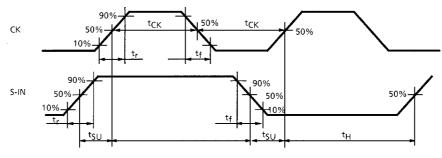
TEST CIRCUIT 7 (Calibrate I_{O} to 0.6 A by R1, 0.5 A by R2)



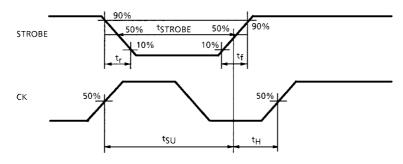
- 7-1. Set the STROBE terminal to high level and compare the output with the data in the waveform shown in Fig.7-1.
- 7–2. Check that the output is latched in the waveform as shown in Fig.7–2.
- 7–3. Check the CK or STROBE, and the output delay time in the waveform as shown in Fig.7–3.
- 7-4. Change the VCC voltage, and check the delay with the output in the waveform as show in Fig.7-4.

AC ELECTRICAL CHARACTERISTICS

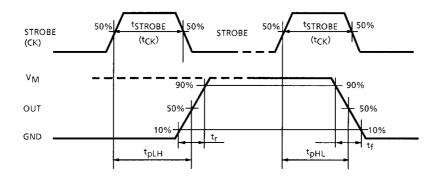
7-1 : CK-S-IN



7-2: STROBE-CK

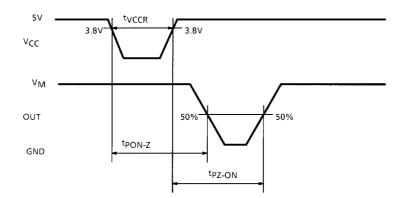


7-3 : STROBE (CK)-OUT



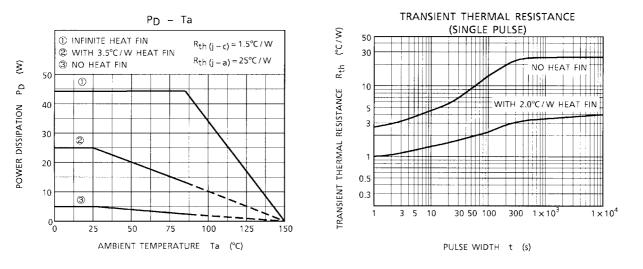
7-4 : V_{CCR}-OUT

TOSHIBA

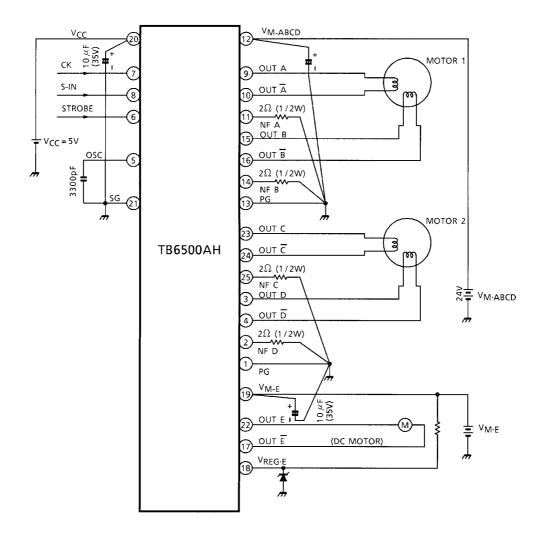


When measuring the upper transistor, set the external load resistor between the output and GND, then measure at the output terminal.

When measuring the lower transistor, set the external load resistor between the output and $V_{\mbox{\scriptsize M}}$ then measure at the output terminal.



APPLICATION CIRCUIT

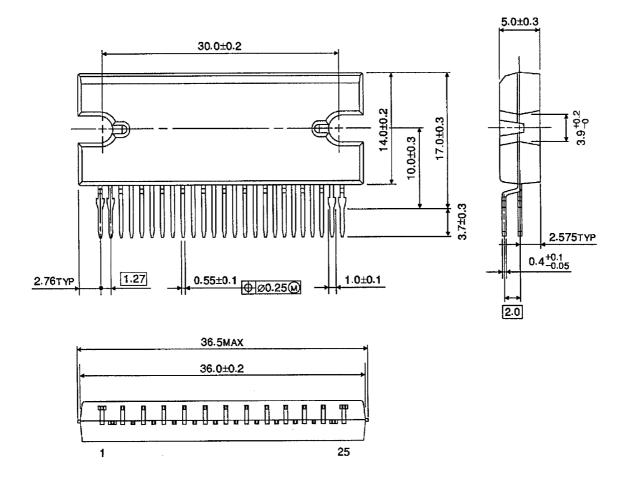


- Note 1: Care should be taken not to have a common impedance with output current pass of each motor (NF A, NF B for MOTOR 1, NF C, MOTOR 2 and PG for DC MOTOR) and any other signal lines. And recommended to take one point GND with each output current pass and corresponding PG terminal. (see table 1 of BLOCK Diagram)
- Note 2: Utmost care is necessary in the design of the output line, V_M and GND line since IC may be destroyed due to short–circuit between outputs, air contamination fault, or fault by improper grounding.

PACKAGE DIMENSIONS

HZIP25-P-1.27

Unit: mm



Weight: 9.86 g (Typ.)

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Handbook" etc..

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